

Publications

- [1] A. Al-Samaneh, S. Renz, D. Wahl, and R. Michalzik, “Small-signal analysis and polarization stability performance of single-mode VCSELs for MEMS atomic clock applications”, in Proc. *Sixth Joint Symposium on Opto- and Microelectronic Devices and Circuits, SODC2010*, pp. 61–64. Berlin, Germany, Oct. 2010.
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